

BCR8AS-14LJ

Triac Medium Power Use R07DS0514EJ0100 Rev.1.00 Oct 14, 2011

Features

I_{T (RMS)}: 8 A
 V_{DRM}: 700 V

 $\bullet \quad I_{FGTI},\,I_{RGTI},\,I_{RGT\,III}:30\;mA$

- Non-Insulated Type
- Planar Type
- Surface Mounted type

Outline

RENESAS Package code: PRSS0004ZG-A (Package name: MP-3A)

123



- 1. T₁ Terminal
- 2. T₂ Terminal
- 3. Gate Terminal
- 4. T₂ Terminal

Applications

Washing machine, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
Farameter	Syllibol	14	Onit
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	700	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	8	Α	Commercial frequency, sine full wave
				360°conduction, Tc =97°C
Surge on-state current	I _{TSM}	80	Α	60 Hz sinewave 1 full cycle, peak value,
				non-repetitive
I ² t for fusion	l ² t	26	A ² s	Value corresponding to 1 cycle of half
				wave 60 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction Temperature	Tj	-40 to +125	°C	
Storage temperature	Tstg	-40 to +125	°C	
Mass	_	0.32	g	Typical value

Electrical Characteristics

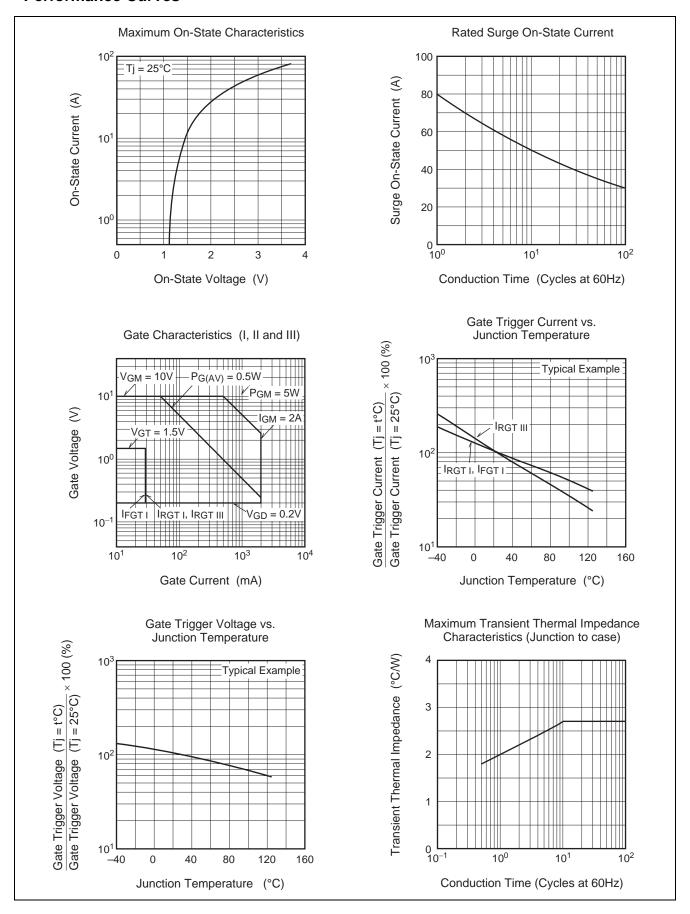
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I _{DRM}			2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V_{TM}	_	_	1.6	V	Tc = 25°C, I _{TM} = 12 A,
							instantaneous measurement
Gate trigger voltage ^{Note2}	I	$V_{FGT_{\mathrm{I}}}$	_	_	1.5	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	$V_{RGT_{\rm I}}$	_	_	1.5	V	$R_G = 330 \Omega$
	III	$V_{RGT_{III}}$	_	_	1.5	V	
Gate trigger curent ^{Note2}	I	I_{FGTI}	_	_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	I_{RGTI}	_	_	30	mA	$R_G = 330 \Omega$
	III	I _{RGTIII}	_	_	30	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	_	_	2.7	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-stat	te	(dv/dt)c	10	_	_	V/μs	Tj = 125°C
commutation voltage ^{Note4}							

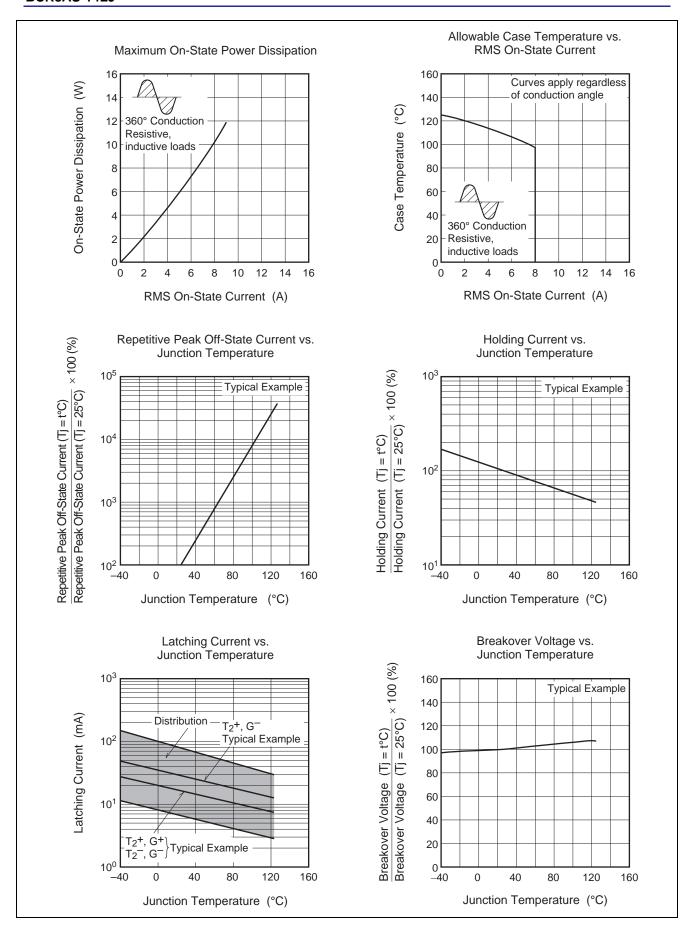
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

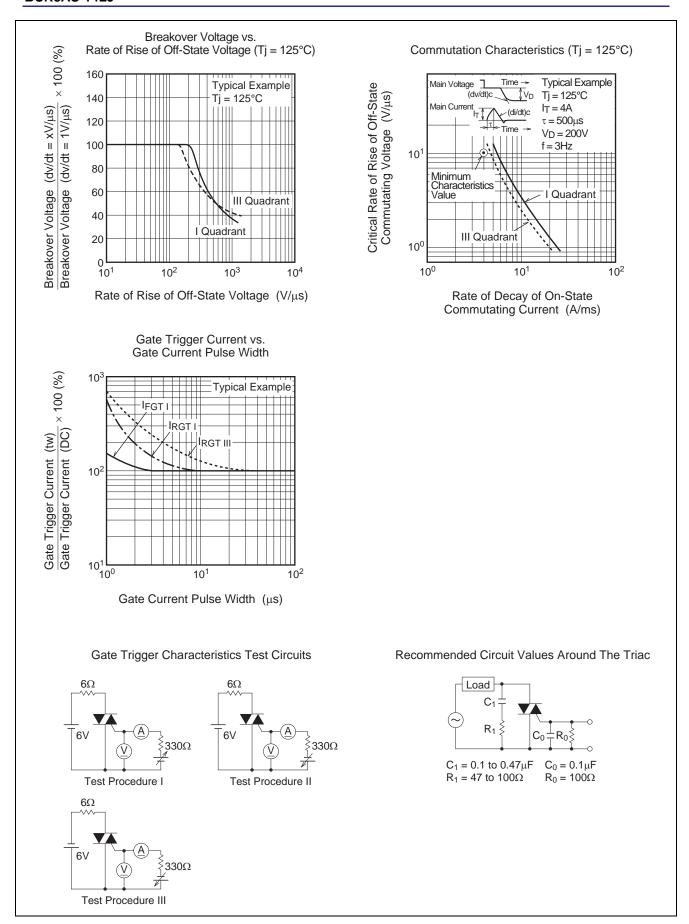
- 3. Case temperature is measured on the T_2 tab.
- 4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C	Supply Voltage -Time
2. Rate of decay of on-state commutating current (di/dt)c = -4.0 A/ms	Main Current (di/dt)c
3. Peak off-state voltage V _D = 400 V	Main Voltage Time

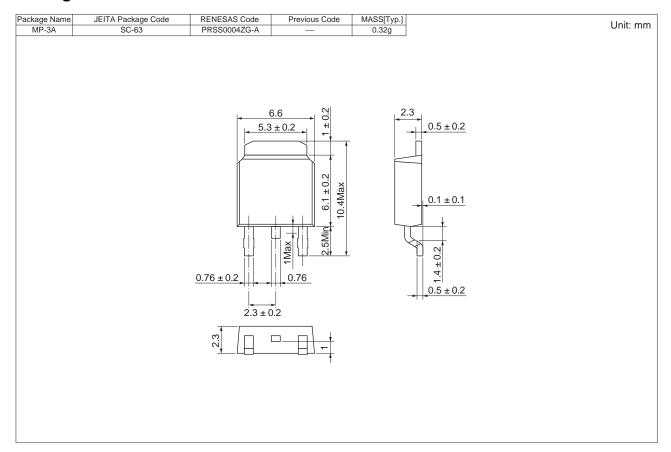
Performance Curves







Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR8AS-14LJ#B01	Tube	75 pcs.	MP-3A package
BCR8AS14LJ-T13#B01	Embossed Tape	3000 pcs.	MP-3A package, Taping direction "T1"

Note: Please confirm the specification about the shipping in detail.

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